Dual General Purpose Transistor

The NST3904DP6T5G device is a spin-off of our popular SOT-23/SOT-323/SOT-563 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-963 six-leaded surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

Features

- h_{FE}, 100-300
- Low $V_{CE(sat)}$, $\leq 0.4 V$
- Reduces Board Space and Component Count
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector – Emitter Voltage		V _{CEO}	40	Vdc
Collector - Base Voltage		V _{CBO}	60	Vdc
Emitter – Base Voltage		V _{EBO}	6.0	Vdc
Collector Current – Continuous		۱ _C	200	mAdc
Electrostatic Discharge	HBM MM	ESD Class	2 B	

THERMAL CHARACTERISTICS

Characteristic (Single Heated)	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C Derate above 25°C (Note 1)	P _D	240 1.9	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	R_{\thetaJA}	520	°C/W
Total Device Dissipation T _A = 25°C Derate above 25°C (Note 2)	P _D	280 2.2	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	446	°C/W
Characteristic (Dual Heated) (Note 3)	Symbol	Мах	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C (Note 1)	P _D	350 2.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	357	°C/W
Total Device Dissipation T _A = 25°C Derate above 25°C (Note 2)	P _D	420 3.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	297	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	– 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

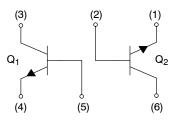
FR-4 @ 100 mm², 1 oz. copper traces, still air.
FR-4 @ 500 mm², 1 oz. copper traces, still air.

3. Dual heated values assume total power is sum of two equally powered channels.



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NST3904DP6T5G



SOT-963 CASE 527AD

MARKING DIAGRAM



= Device Code F Μ = Date Code

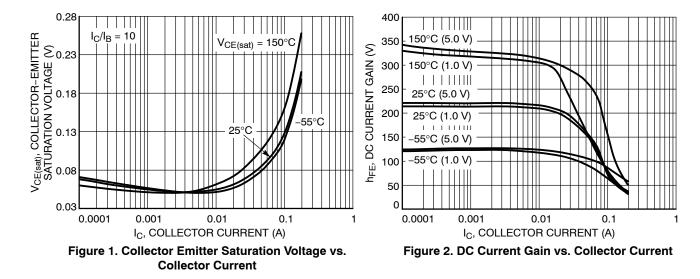
ORDERING INFORMATION

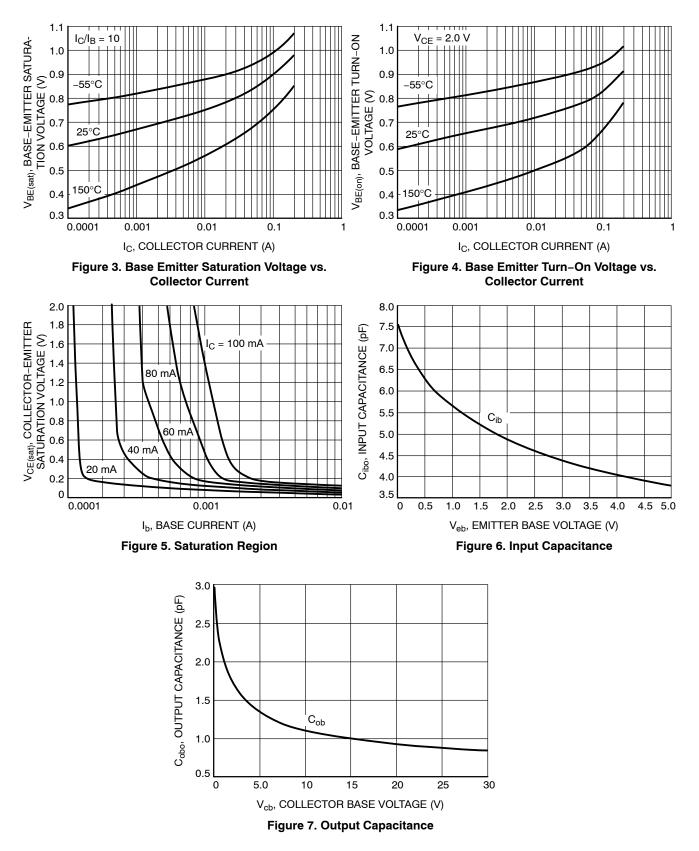
Device	Package	Shipping [†]
NST3904DP6T5G	SOT-963 (Pb-Free)	8000/Tape & Reel
NSVT3904DP6T5G	SOT-963 (Pb-Free)	8000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

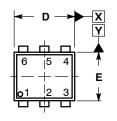
Characteristic		Symbol	Min	Max	Unit	
OFF CHARACTERISTICS				•		
Collector – Emitter Breakdown Voltage (Note 4) ($I_c = 1.0 \text{ mAdc}, I_B = 0$)		V _{(BR)CEO}	40	-	Vdc	
Collector - Base Breakdown Volta	ge (I _C = 10 μAdc, I _E = 0)	V _{(BR)CBO}	60	-	Vdc	
Emitter – Base Breakdown Voltage ($I_E = 10 \ \mu$ Adc, $I_C = 0$)		V _{(BR)EBO}	6.0	-	Vdc	
Collector Cutoff Current (V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc)		I _{CEX}	-	50	nAdc	
ON CHARACTERISTICS (Note 4)		L			
DC Current Gain ($I_C = 0.1 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 1.0 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 50 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$) ($I_C = 100 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}$)		h _{FE}	40 70 100 60 30	- - 300 - -	-	
Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$)		V _{CE(sat)}		0.2 0.3	Vdc	
Base – Emitter Saturation Voltage $(I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc})$ $(I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc})$		V _{BE(sat)}	0.65 -	0.85 0.95	Vdc	
SMALL-SIGNAL CHARACTERI	STICS		L			
Current – Gain – Bandwidth Product (I_C = 10 mAdc, V_{CE} = 20 Vdc, f = 100 MHz)		f _T	200	-	MHz	
Output Capacitance (V _{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz)		C _{obo}	_	4.0	pF	
Input Capacitance (V_{EB} = 0.5 Vdc, I_C = 0, f = 1.0 MHz)		C _{ibo}	-	8.0	pF	
Noise Figure (V _{CE} = 5.0 Vdc, I _C = 100 μ Adc, R _S = 1.0 k Ω , f = 1.0 kHz)		NF	-	5.0	dB	
SWITCHING CHARACTERISTIC	S					
Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc})$	t _d	-	35	ns	
Rise Time	(I _C = 10 mAdc, I _{B1} = 1.0 mAdc)	t _r	-	35		
Storage Time	(V _{CC} = 3.0 Vdc, I _C = 10 mAdc)	t _s	-	275	ns	
Fall Time	(I _{B1} = I _{B2} = 1.0 mAdc)	t _f	-	50		



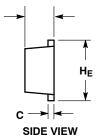


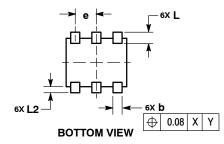
PACKAGE DIMENSIONS

SOT-963 CASE 527AD ISSUE E



TOP VIEW





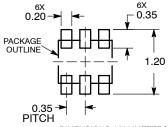
NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS

2. CONTROLLING DIMENSION: MILLIMETERS 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF

BASE MATERIAL. 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.34	0.37	0.40	
b	0.10	0.15	0.20	
С	0.07	0.12	0.17	
D	0.95	1.00	1.05	
E	0.75	0.80	0.85	
е	0.35 BSC			
ΗE	0.95	1.00	1.05	
L	0.19 REF			
L2	0.05	0.10	0.15	

RECOMMENDED MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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